

R-C Thermal Model Parameters

DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. These techniques are described in "[A Simple Method of Generating Thermal Models for a Power MOSFET](#)"[1]. When implemented in P-Spice, these values have matching characteristic curves to the Single Pulse Transient Thermal Impedance curves for the MOSFET.

R-C values for the electrical circuit in the Foster/Tank and Cauer/Filter configurations are included.

Note:

For a detailed explanation of implementing these values in P-SPICE, refer to [Application Note AN609 Thermal Simulations Of Power MOSFETs on P-SPICE Platform](#).

R-C THERMAL MODEL FOR TANK CONFIGURATION



R-C VALUES FOR TANK CONFIGURATION			
Thermal Resistance (°C/W)			
Junction to	Ambient	Case	Foot
RT1	19.1036	N/A	25.3798
RT2	25.5205	N/A	2.5489
RT3	47.7695	N/A	22.3544
RT4	57.6064	N/A	14.7169
Thermal Capacitance (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	4.3465 m	N/A	51.9284 m
CT2	73.6456 m	N/A	709.3105 u
CT3	13.4212 m	N/A	13.6243 m
CT4	1.8430	N/A	6.5796 m

This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.

R-C THERMAL MODEL FOR FILTER CONFIGURATION**R-C VALUES FOR FILTER CONFIGURATION**

Thermal Resistance ($^{\circ}\text{C}/\text{W}$)			
Junction to	Ambient	Case	Foot
RF1	14.2189	N/A	7.1047
RF2	43.3463	N/A	24.8253
RF3	36.2532	N/A	26.8763
RF4	56.1816	N/A	6.1937
Thermal Capacitance (Joules/ $^{\circ}\text{C}$)			
Junction to	Ambient	Case	Foot
CF1	2.2763 m	N/A	1.3291 m
CF2	3.9764 m	N/A	3.1493 m
CF3	23.0874 m	N/A	13.8658 m
CF4	1.8550	N/A	318.6923 m

Note: NA indicates not applicable

Reference:

[1] "A Simple Method of Generating Thermal Models for a Power MOSFET" by Wharton McDaniel and Kandarp Pandya. IEEE / SEMITHERM 2002

